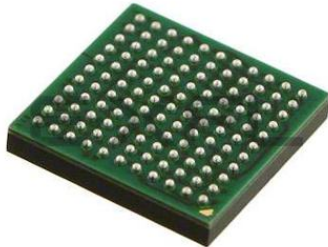


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### What is "[Embedded - Microcontrollers](#)"?



"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	72MHz
Connectivity	I <sup>2</sup> C, IrDA, SPI, UART/USART, USB, USB OTG
Peripherals	DMA, I <sup>2</sup> S, LVD, POR, PWM, WDT
Number of I/O	78
Program Memory Size	256KB (256K x 8)
Program Memory Type	FLASH
EEPROM Size	2K x 8
RAM Size	64K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 3.6V
Data Converters	A/D 35x16b; D/A 1x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	121-LFBGA
Supplier Device Package	121-MAPBGA (8x8)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/mk51dx256cmc7">https://www.e-xfl.com/product-detail/nxp-semiconductors/mk51dx256cmc7</a>

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# 1 Ordering parts

## 1.1 Determining valid orderable parts

Valid orderable part numbers are provided on the web. To determine the orderable part numbers for this device, go to [www.freescale.com](http://www.freescale.com) and perform a part number search for the following device numbers: PK51 and MK51.

# 2 Part identification

## 2.1 Description

Part numbers for the chip have fields that identify the specific part. You can use the values of these fields to determine the specific part you have received.

## 2.2 Format

Part numbers for this device have the following format:

Q K## A M FFF R T PP CC N

## 2.3 Fields

This table lists the possible values for each field in the part number (not all combinations are valid):

Field	Description	Values
Q	Qualification status	<ul style="list-style-type: none"> <li>M = Fully qualified, general market flow</li> <li>P = Prequalification</li> </ul>
K##	Kinetis family	<ul style="list-style-type: none"> <li>K51</li> </ul>
A	Key attribute	<ul style="list-style-type: none"> <li>D = Cortex-M4 w/ DSP</li> <li>F = Cortex-M4 w/ DSP and FPU</li> </ul>
M	Flash memory type	<ul style="list-style-type: none"> <li>N = Program flash only</li> <li>X = Program flash and FlexMemory</li> </ul>

*Table continues on the next page...*

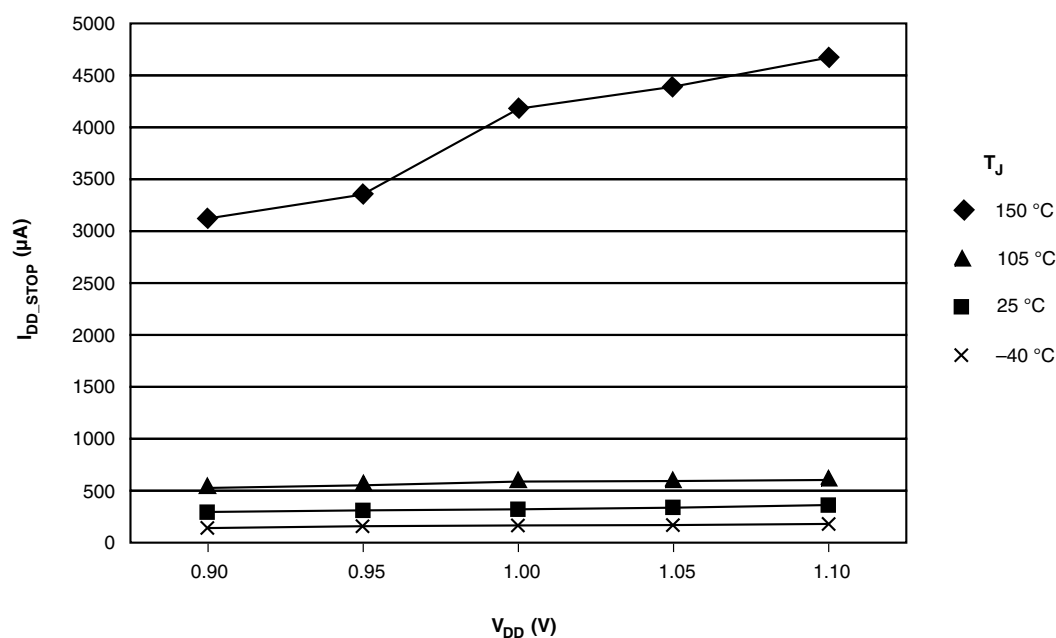
### 3.8.1 Example 1

This is an example of an operating behavior that includes a typical value:

Symbol	Description	Min.	Typ.	Max.	Unit
$I_{WP}$	Digital I/O weak pullup/pulldown current	10	70	130	$\mu\text{A}$

### 3.8.2 Example 2

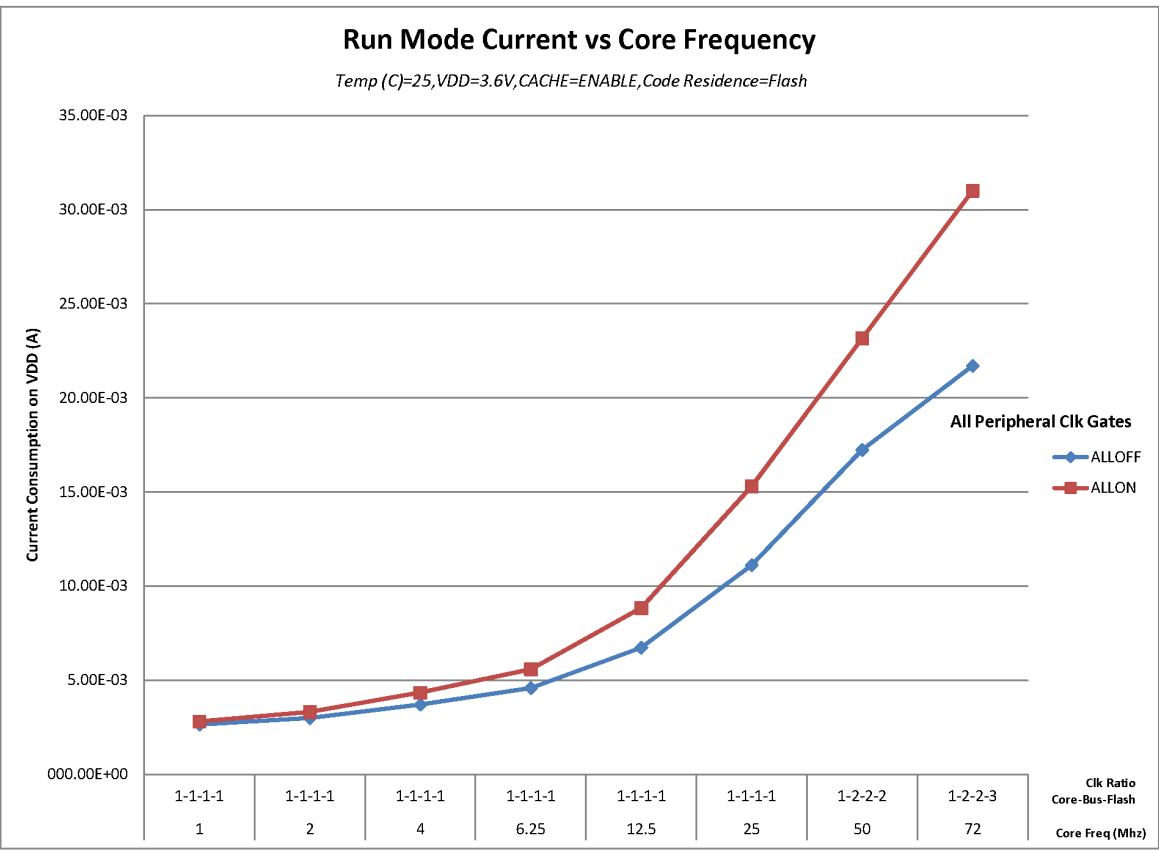
This is an example of a chart that shows typical values for various voltage and temperature conditions:



## 3.9 Typical value conditions

Typical values assume you meet the following conditions (or other conditions as specified):

Symbol	Description	Value	Unit
$T_A$	Ambient temperature	25	$^{\circ}\text{C}$
$V_{DD}$	3.3 V supply voltage	3.3	V



**Figure 2. Run mode supply current vs. core frequency**

## 5.4.2 Thermal attributes

Board type	Symbol	Description	121 MAPBGA	100 LQFP	Unit	Notes
Single-layer (1s)	$R_{\theta JA}$	Thermal resistance, junction to ambient (natural convection)	74	52	°C/W	1, 2
Four-layer (2s2p)	$R_{\theta JA}$	Thermal resistance, junction to ambient (natural convection)	42	40	°C/W	1, 3
Single-layer (1s)	$R_{\theta JMA}$	Thermal resistance, junction to ambient (200 ft./min. air speed)	62	42	°C/W	1,3
Four-layer (2s2p)	$R_{\theta JMA}$	Thermal resistance, junction to ambient (200 ft./min. air speed)	38	34	°C/W	1,3
—	$R_{\theta JB}$	Thermal resistance, junction to board	23	25	°C/W	4
—	$R_{\theta JC}$	Thermal resistance, junction to case	19	12	°C/W	5
—	$\Psi_{JT}$	Thermal characterization parameter, junction to package top outside center (natural convection)	4	2	°C/W	6

1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
2. Determined according to JEDEC Standard JESD51-2, *Integrated Circuits Thermal Test Method Environmental Conditions—Natural Convection (Still Air)* with the single layer board horizontal. For the LQFP, the board meets the JESD51-3 specification. For the MAPBGA, the board meets the JESD51-9 specification.
3. Determined according to JEDEC Standard JESD51-6, *Integrated Circuits Thermal Test Method Environmental Conditions—Forced Convection (Moving Air)* with the board horizontal. For the LQFP, the board meets the JESD51-7 specification.
4. Determined according to JEDEC Standard JESD51-8, *Integrated Circuit Thermal Test Method Environmental Conditions—Junction-to-Board*. Board temperature is measured on the top surface of the board near the package.

5. Determined according to Method 1012.1 of MIL-STD 883, *Test Method Standard, Microcircuits*, with the cold plate temperature used for the case temperature. The value includes the thermal resistance of the interface material between the top of the package and the cold plate.
6. Determined according to JEDEC Standard JESD51-2, *Integrated Circuits Thermal Test Method Environmental Conditions—Natural Convection (Still Air)*.

## 6 Peripheral operating requirements and behaviors

### 6.1 Core modules

#### 6.1.1 Debug trace timing specifications

Table 11. Debug trace operating behaviors

Symbol	Description	Min.	Max.	Unit
$T_{cyc}$	Clock period	Frequency dependent		MHz
$T_{wl}$	Low pulse width	2	—	ns
$T_{wh}$	High pulse width	2	—	ns
$T_r$	Clock and data rise time	—	3	ns
$T_f$	Clock and data fall time	—	3	ns
$T_s$	Data setup	3	—	ns
$T_h$	Data hold	2	—	ns

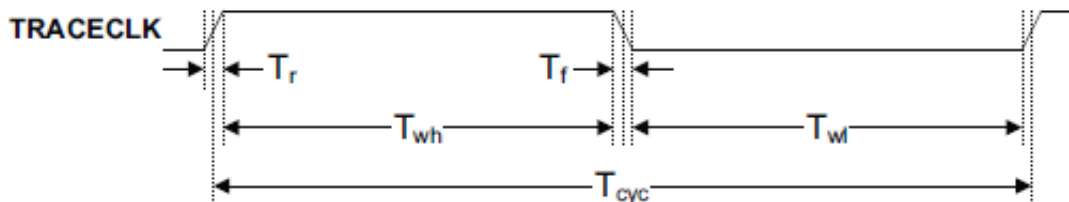


Figure 4. TRACE\_CLKOUT specifications

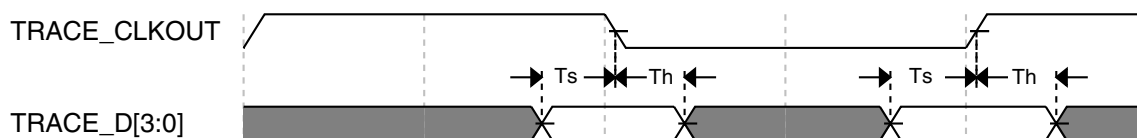


Figure 5. Trace data specifications

- Crystal startup time is defined as the time between the oscillator being enabled and the OSCINIT bit in the MCG\_S register being set.

### NOTE

The 32 kHz oscillator works in low power mode by default and cannot be moved into high power/gain mode.

## 6.3.3 32 kHz Oscillator Electrical Characteristics

This section describes the module electrical characteristics.

### 6.3.3.1 32 kHz oscillator DC electrical specifications

Table 17. 32kHz oscillator DC electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit
$V_{BAT}$	Supply voltage	1.71	—	3.6	V
$R_F$	Internal feedback resistor	—	100	—	$M\Omega$
$C_{para}$	Parasitical capacitance of EXTAL32 and XTAL32	—	5	7	pF
$V_{pp}$ <sup>1</sup>	Peak-to-peak amplitude of oscillation	—	0.6	—	V

- When a crystal is being used with the 32 kHz oscillator, the EXTAL32 and XTAL32 pins should only be connected to required oscillator components and must not be connected to any other devices.

### 6.3.3.2 32kHz oscillator frequency specifications

Table 18. 32kHz oscillator frequency specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$f_{osc\_lo}$	Oscillator crystal	—	32.768	—	kHz	
$t_{start}$	Crystal start-up time	—	1000	—	ms	1
$V_{ec\_extal32}$	Externally provided input clock amplitude	700	—	$V_{BAT}$	mV	2, 3

- Proper PC board layout procedures must be followed to achieve specifications.
- This specification is for an externally supplied clock driven to EXTAL32 and does not apply to any other clock input. The oscillator remains enabled and XTAL32 must be left unconnected.
- The parameter specified is a peak-to-peak value and  $V_{IH}$  and  $V_{IL}$  specifications do not apply. The voltage of the applied clock must be within the range of  $V_{SS}$  to  $V_{BAT}$ .

## 6.4 Memories and memory interfaces

### 6.4.1 Flash electrical specifications

This section describes the electrical characteristics of the flash memory module.



### 6.4.1.1 Flash timing specifications — program and erase

The following specifications represent the amount of time the internal charge pumps are active and do not include command overhead.

**Table 19. NVM program/erase timing specifications**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{hvp\text{gm}4}$	Longword Program high-voltage time	—	7.5	18	$\mu\text{s}$	
$t_{h\text{versscr}}$	Sector Erase high-voltage time	—	13	113	ms	1
$t_{h\text{versblk}32\text{k}}$	Erase Block high-voltage time for 32 KB	—	52	452	ms	1
$t_{h\text{versblk}256\text{k}}$	Erase Block high-voltage time for 256 KB	—	104	904	ms	1

1. Maximum time based on expectations at cycling end-of-life.

### 6.4.1.2 Flash timing specifications — commands

**Table 20. Flash command timing specifications**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{rd1\text{blk}32\text{k}}$	Read 1s Block execution time					
	<ul style="list-style-type: none"> <li>32 KB data flash</li> </ul>	—	—	0.5	ms	
$t_{rd1\text{blk}256\text{k}}$	<ul style="list-style-type: none"> <li>256 KB program flash</li> </ul>	—	—	1.7	ms	
$t_{rd1\text{sec}1\text{k}}$	Read 1s Section execution time (data flash sector)	—	—	60	$\mu\text{s}$	1
$t_{rd1\text{sec}2\text{k}}$	Read 1s Section execution time (program flash sector)	—	—	60	$\mu\text{s}$	1
$t_{pgm\text{chk}}$	Program Check execution time	—	—	45	$\mu\text{s}$	1
$t_{rd\text{rsrc}}$	Read Resource execution time	—	—	30	$\mu\text{s}$	1
$t_{pgm4}$	Program Longword execution time	—	65	145	$\mu\text{s}$	
$t_{ers\text{blk}32\text{k}}$	Erase Flash Block execution time					2
	<ul style="list-style-type: none"> <li>32 KB data flash</li> </ul>	—	55	465	ms	
$t_{ers\text{blk}256\text{k}}$	<ul style="list-style-type: none"> <li>256 KB program flash</li> </ul>	—	122	985	ms	
$t_{ers\text{scr}}$	Erase Flash Sector execution time	—	14	114	ms	2
$t_{pgm\text{sec}512\text{p}}$	Program Section execution time					
	<ul style="list-style-type: none"> <li>512 B program flash</li> </ul>	—	2.4	—	ms	
$t_{pgm\text{sec}512\text{d}}$	<ul style="list-style-type: none"> <li>512 B data flash</li> </ul>	—	4.7	—	ms	
$t_{pgm\text{sec}1\text{kp}}$	<ul style="list-style-type: none"> <li>1 KB program flash</li> </ul>	—	4.7	—	ms	
$t_{pgm\text{sec}1\text{kd}}$	<ul style="list-style-type: none"> <li>1 KB data flash</li> </ul>	—	9.3	—	ms	
$t_{rd1\text{all}}$	Read 1s All Blocks execution time	—	—	1.8	ms	
$t_{rd\text{once}}$	Read Once execution time	—	—	25	$\mu\text{s}$	1
$t_{pgm\text{once}}$	Program Once execution time	—	65	—	$\mu\text{s}$	
$t_{ers\text{all}}$	Erase All Blocks execution time	—	175	1500	ms	2

Table continues on the next page...

**Table 20. Flash command timing specifications (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{\text{vfykey}}$	Verify Backdoor Access Key execution time	—	—	30	$\mu\text{s}$	1
$t_{\text{swapx01}}$	Swap Control execution time					
	• control code 0x01	—	200	—	$\mu\text{s}$	
$t_{\text{swapx02}}$	• control code 0x02	—	70	150	$\mu\text{s}$	
$t_{\text{swapx04}}$	• control code 0x04	—	70	150	$\mu\text{s}$	
$t_{\text{swapx08}}$	• control code 0x08	—	—	30	$\mu\text{s}$	
$t_{\text{pgmpart32k}}$	Program Partition for EEPROM execution time					
	• 32 KB FlexNVM	—	70	—	ms	
$t_{\text{setramff}}$	Set FlexRAM Function execution time:					
	• Control Code 0xFF	—	50	—	$\mu\text{s}$	
$t_{\text{setram8k}}$	• 8 KB EEPROM backup	—	0.3	0.5	ms	
$t_{\text{setram32k}}$	• 32 KB EEPROM backup	—	0.7	1.0	ms	
Byte-write to FlexRAM for EEPROM operation						
$t_{\text{eewr8bers}}$	Byte-write to erased FlexRAM location execution time	—	175	260	$\mu\text{s}$	3
$t_{\text{eewr8b8k}}$	Byte-write to FlexRAM execution time:					
	• 8 KB EEPROM backup	—	340	1700	$\mu\text{s}$	
$t_{\text{eewr8b16k}}$	• 16 KB EEPROM backup	—	385	1800	$\mu\text{s}$	
$t_{\text{eewr8b32k}}$	• 32 KB EEPROM backup	—	475	2000	$\mu\text{s}$	
Word-write to FlexRAM for EEPROM operation						
$t_{\text{eewr16bers}}$	Word-write to erased FlexRAM location execution time	—	175	260	$\mu\text{s}$	
$t_{\text{eewr16b8k}}$	Word-write to FlexRAM execution time:					
	• 8 KB EEPROM backup	—	340	1700	$\mu\text{s}$	
$t_{\text{eewr16b16k}}$	• 16 KB EEPROM backup	—	385	1800	$\mu\text{s}$	
$t_{\text{eewr16b32k}}$	• 32 KB EEPROM backup	—	475	2000	$\mu\text{s}$	
Longword-write to FlexRAM for EEPROM operation						
$t_{\text{eewr32bers}}$	Longword-write to erased FlexRAM location execution time	—	360	540	$\mu\text{s}$	
$t_{\text{eewr32b8k}}$	Longword-write to FlexRAM execution time:					
	• 8 KB EEPROM backup	—	545	1950	$\mu\text{s}$	
$t_{\text{eewr32b16k}}$	• 16 KB EEPROM backup	—	630	2050	$\mu\text{s}$	
$t_{\text{eewr32b32k}}$	• 32 KB EEPROM backup	—	810	2250	$\mu\text{s}$	

1. Assumes 25 MHz flash clock frequency.
2. Maximum times for erase parameters based on expectations at cycling end-of-life.
3. For byte-writes to an erased FlexRAM location, the aligned word containing the byte must be erased.

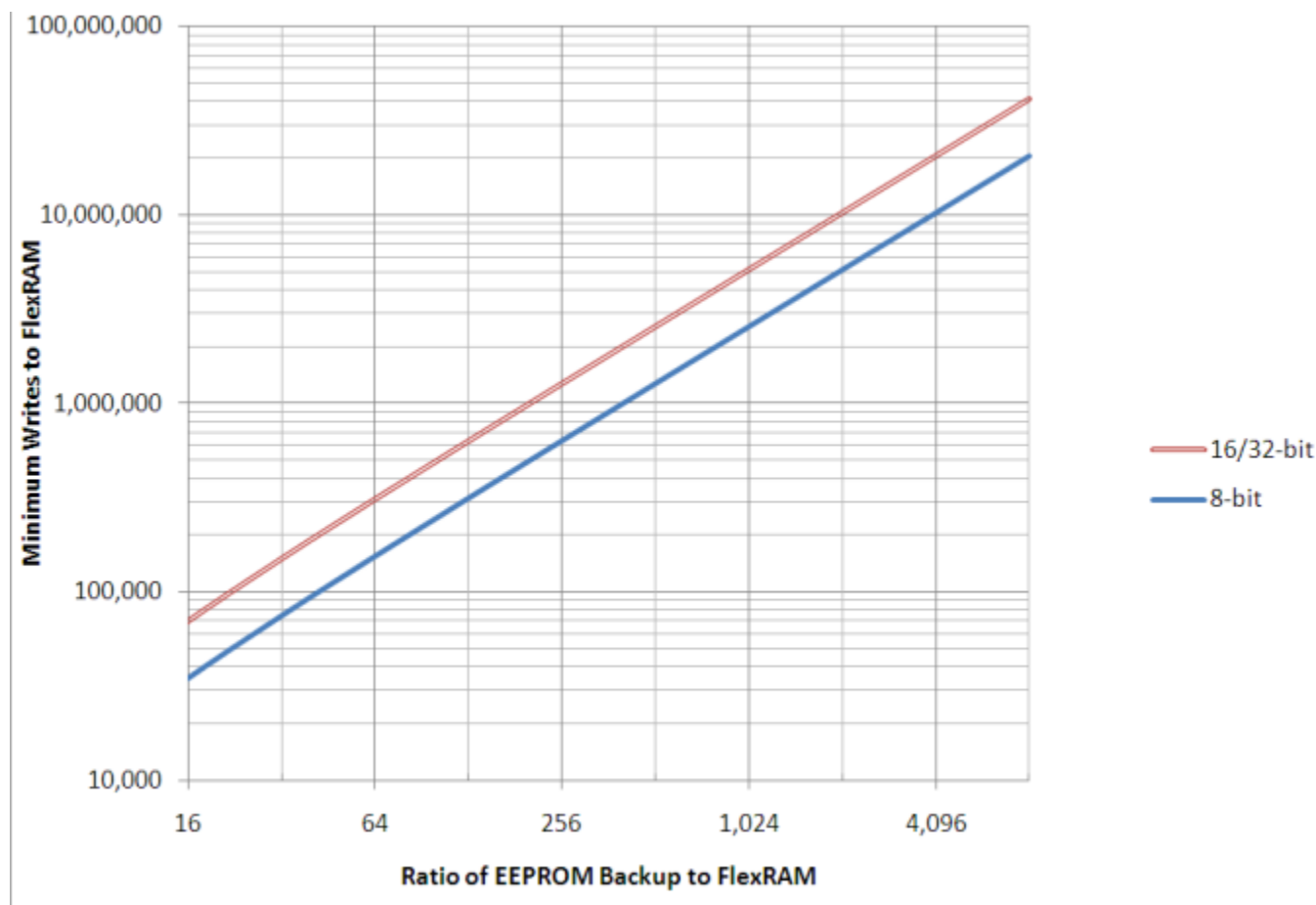


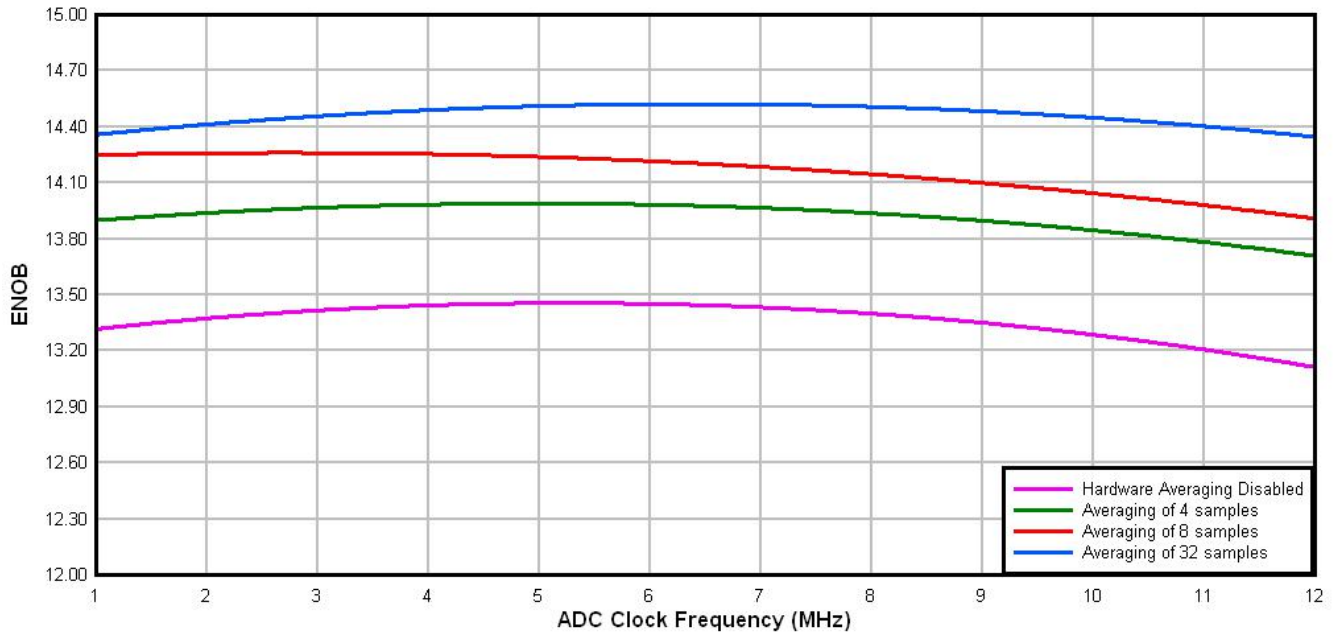
Figure 10. EEPROM backup writes to FlexRAM

## 6.4.2 EzPort Switching Specifications

Table 23. EzPort switching specifications

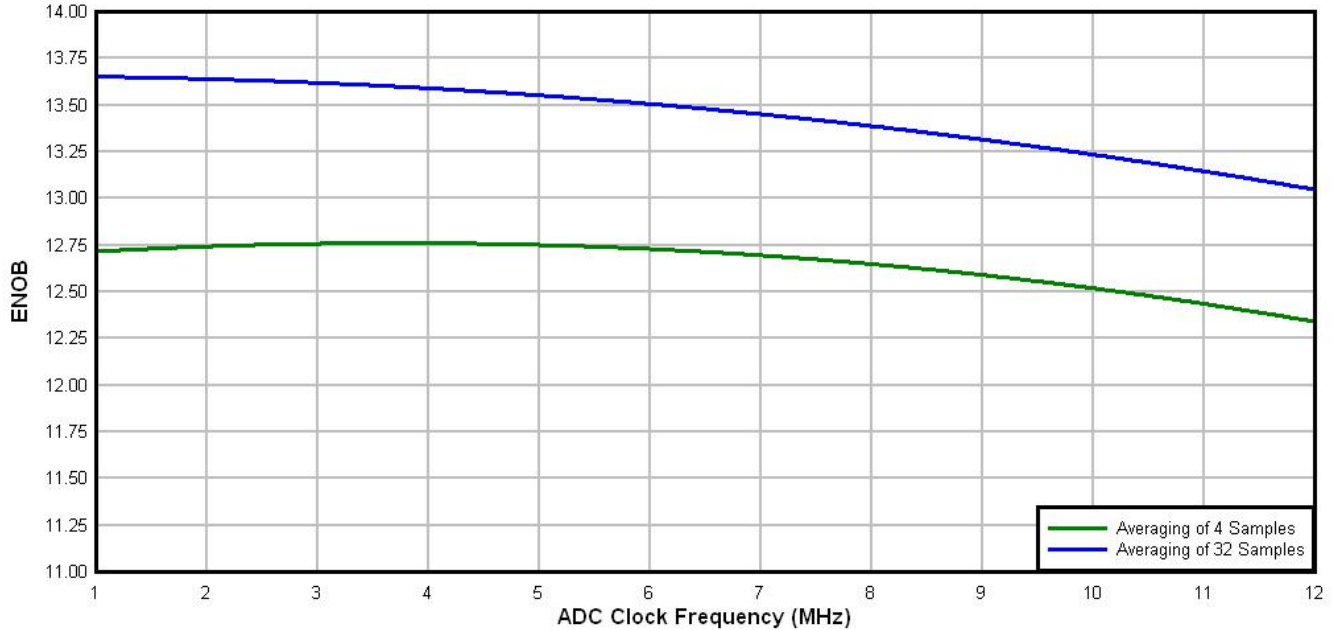
Num	Description	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
EP1	EZP_CK frequency of operation (all commands except READ)	—	$f_{SYS}/2$	MHz
EP1a	EZP_CK frequency of operation (READ command)	—	$f_{SYS}/8$	MHz
EP2	EZP_CS negation to next EZP_CS assertion	$2 \times t_{EZP\_CK}$	—	ns
EP3	EZP_CS input valid to EZP_CK high (setup)	5	—	ns
EP4	EZP_CK high to EZP_CS input invalid (hold)	5	—	ns
EP5	EZP_D input valid to EZP_CK high (setup)	2	—	ns
EP6	EZP_CK high to EZP_D input invalid (hold)	5	—	ns
EP7	EZP_CK low to EZP_Q output valid	—	16	ns
EP8	EZP_CK low to EZP_Q output invalid (hold)	0	—	ns
EP9	EZP_CS negation to EZP_Q tri-state	—	12	ns

**Typical ADC 16-bit Differential ENOB vs ADC Clock**  
**100Hz, 90% FS Sine Input**



**Figure 13. Typical ENOB vs. ADC\_CLK for 16-bit differential mode**

**Typical ADC 16-bit Single-Ended ENOB vs ADC Clock**  
**100Hz, 90% FS Sine Input**



**Figure 14. Typical ENOB vs. ADC\_CLK for 16-bit single-ended mode**

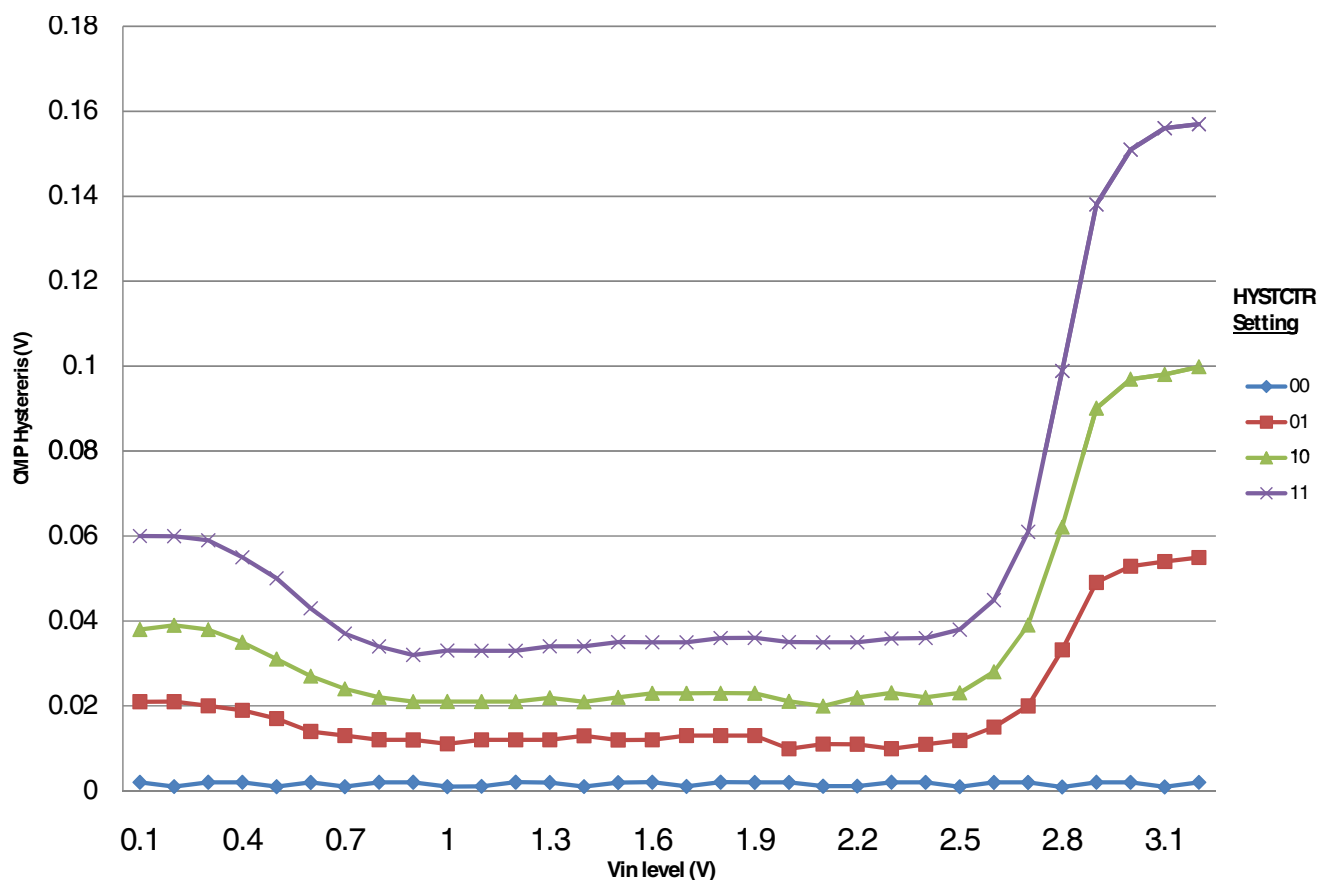


Figure 16. Typical hysteresis vs. Vin level (VDD=3.3V, PMODE=1)

## 6.6.3 12-bit DAC electrical characteristics

### 6.6.3.1 12-bit DAC operating requirements

Table 29. 12-bit DAC operating requirements

Symbol	Description	Min.	Max.	Unit	Notes
$V_{DDA}$	Supply voltage	1.71	3.6	V	
$V_{DACR}$	Reference voltage	1.13	3.6	V	1
$T_A$	Temperature	Operating temperature range of the device		°C	
$C_L$	Output load capacitance	—	100	pF	2
$I_L$	Output load current	—	1	mA	

1. The DAC reference can be selected to be  $V_{DDA}$  or the voltage output of the VREF module (VREF\_OUT)
2. A small load capacitance (47 pF) can improve the bandwidth performance of the DAC

**Table 33. TRIAMP full range operating behaviors**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
I <sub>SUPPLY</sub>	Supply current (I <sub>OUT</sub> =0mA, CL=0) — Low-power mode	—	60	80	μA	
I <sub>SUPPLY</sub>	Supply current (I <sub>OUT</sub> =0mA, CL=0) — High-speed mode	—	280	450	μA	
V <sub>OS</sub>	Input offset voltage	—	±3	±5	mV	
α <sub>VOS</sub>	Input offset voltage temperature coefficient	—	4.8	—	μV/C	
I <sub>OS</sub>	Input offset current	—	±0.3	±5	nA	
I <sub>BIAS</sub>	Input bias current	—	±0.3	±5	nA	
R <sub>IN</sub>	Input resistance	500	—	—	MΩ	
C <sub>IN</sub>	Input capacitance	—	17	—	pF	
R <sub>OUT</sub>	Output AC impedance	—	—	1500	Ω	@ 100kHz, High speed mode
X <sub>IN</sub>	AC input impedance (f <sub>IN</sub> =100kHz)	—	159	—	kΩ	
CMRR	Input common mode rejection ratio	60	—	—	dB	
PSRR	Power supply rejection ratio	60	—	—	dB	
SR	Slew rate (ΔV <sub>IN</sub> =100mV) — Low-power mode	0.1	—	—	V/μs	
SR	Slew rate (ΔV <sub>IN</sub> =100mV) — High speed mode	1	—	—	V/μs	
GBW	Unity gain bandwidth — Low-power mode 50pF	0.15	—	—	MHz	
GBW	Unity gain bandwidth — High speed mode 50pF	1	—	—	MHz	
A <sub>V</sub>	DC open-loop voltage gain	80	—	—	dB	
V <sub>OUT</sub>	Output voltage range	0.15	—	V <sub>DD</sub> -0.15	V	
I <sub>OUT</sub>	Output load current	—	±0.5	—	mA	
GM	Gain margin	—	20	—	dB	
PM	Phase margin	50	60	—	deg	
V <sub>n</sub>	Voltage noise density (noise floor) 1kHz	—	280	—	nV/√Hz	
V <sub>n</sub>	Voltage noise density (noise floor) 10kHz	—	100	—	nV/√Hz	

### 6.6.6 Transimpedance amplifier electrical specifications — limited range

**Table 34. TRIAMP limited range operating requirements**

Symbol	Description	Min.	Max.	Unit	Notes
V <sub>DDA</sub>	Supply voltage	2.4	3.3	V	
V <sub>IN</sub>	Input voltage range	0.1	V <sub>DDA</sub> -1.4	V	
T <sub>A</sub>	Temperature	0	50	C	
C <sub>L</sub>	Output load capacitance	—	100	pf	

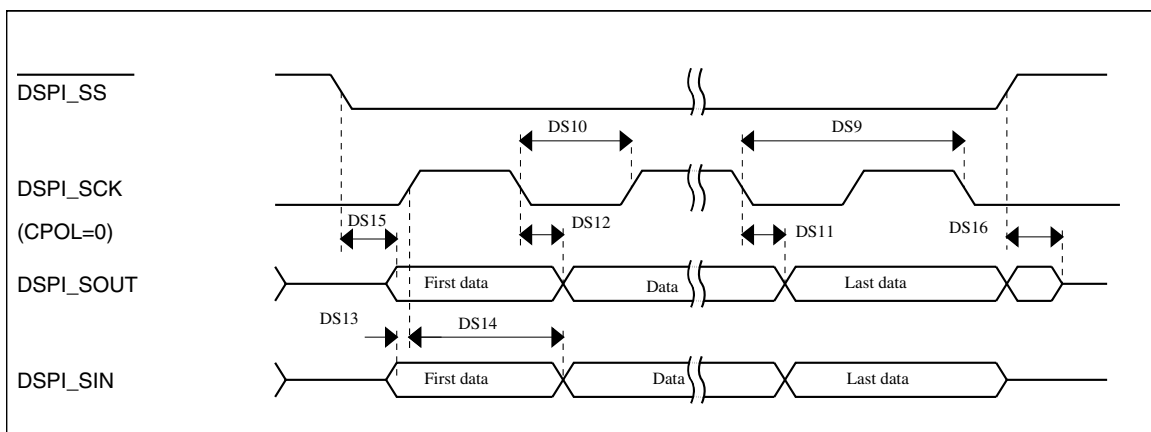


Figure 22. DSPI classic SPI timing — slave mode

### 6.8.6 I<sup>2</sup>C switching specifications

See [General switching specifications](#).

### 6.8.7 UART switching specifications

See [General switching specifications](#).

### 6.8.8 I2S/SAI Switching Specifications

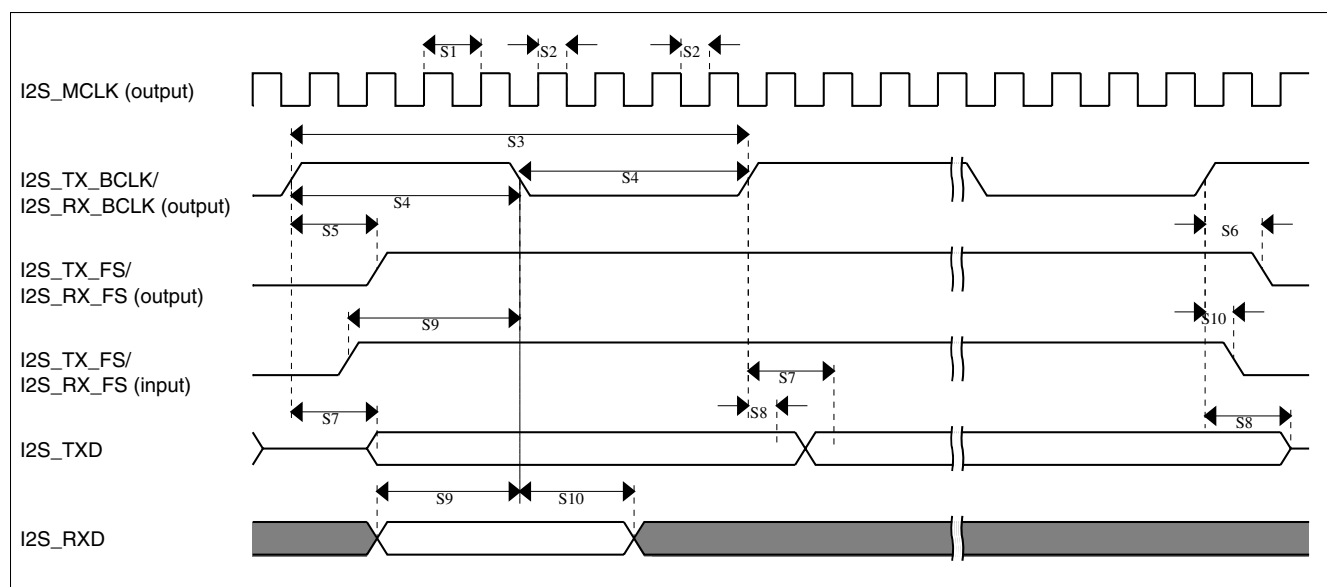
This section provides the AC timing for the I2S/SAI module in master mode (clocks are driven) and slave mode (clocks are input). All timing is given for noninverted serial clock polarity (TCR2[BCP] is 0, RCR2[BCP] is 0) and a noninverted frame sync (TCR4[FSP] is 0, RCR4[FSP] is 0). If the polarity of the clock and/or the frame sync have been inverted, all the timing remains valid by inverting the bit clock signal (BCLK) and/or the frame sync (FS) signal shown in the following figures.

#### 6.8.8.1 Normal Run, Wait and Stop mode performance over the full operating voltage range

This section provides the operating performance over the full operating voltage for the device in Normal Run, Wait and Stop modes.

**Table 46. I2S/SAI master mode timing in Normal Run, Wait and Stop modes (full voltage range)**

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S1	I2S_MCLK cycle time	40	—	ns
S2	I2S_MCLK pulse width high/low	45%	55%	MCLK period
S3	I2S_TX_BCLK/I2S_RX_BCLK cycle time (output)	80	—	ns
S4	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low	45%	55%	BCLK period
S5	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output valid	—	15	ns
S6	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output invalid	-1.0	—	ns
S7	I2S_TX_BCLK to I2S_TXD valid	—	15	ns
S8	I2S_TX_BCLK to I2S_TXD invalid	0	—	ns
S9	I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK	20.5	—	ns
S10	I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK	0	—	ns



**Figure 23. I2S/SAI timing — master modes**

**Table 47. I2S/SAI slave mode timing in Normal Run, Wait and Stop modes (full voltage range)**

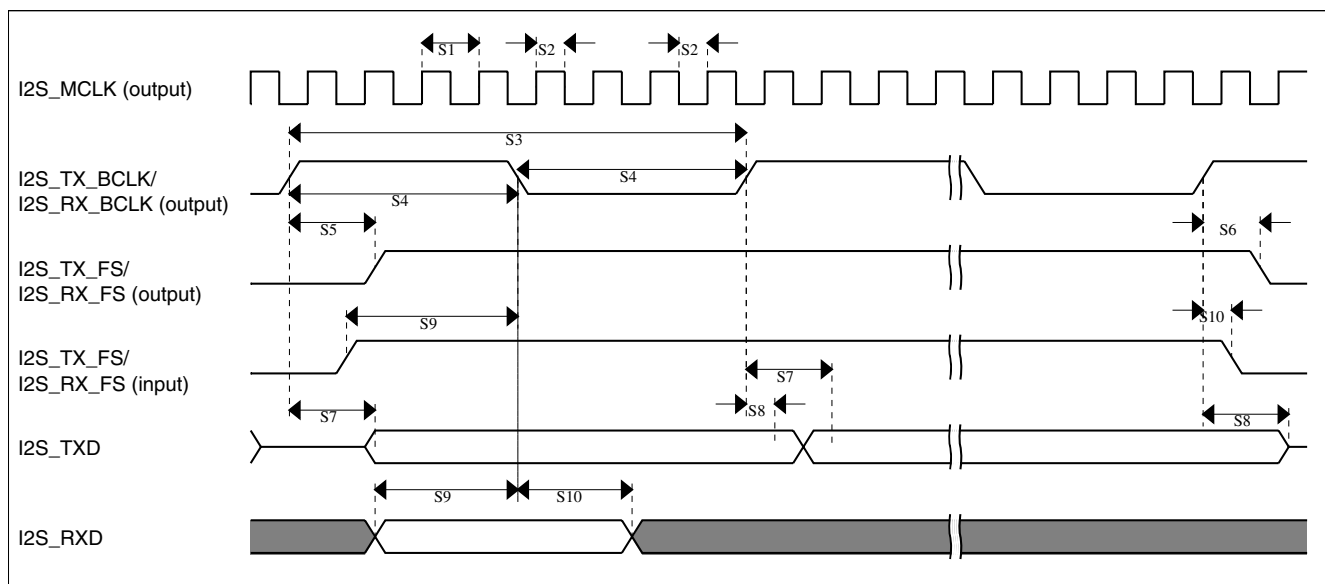
Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S11	I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)	80	—	ns
S12	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low (input)	45%	55%	MCLK period

Table continues on the next page...



**Table 48. I2S/SAI master mode timing in VLPR, VLPW, and VLPS modes (full voltage range) (continued)**

Num.	Characteristic	Min.	Max.	Unit
S5	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output valid	—	45	ns
S6	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output invalid	0	—	ns
S7	I2S_TX_BCLK to I2S_TXD valid	—	45	ns
S8	I2S_TX_BCLK to I2S_TXD invalid	0	—	ns
S9	I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK	53	—	ns
S10	I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK	0	—	ns



**Figure 25. I2S/SAI timing — master modes**

**Table 49. I2S/SAI slave mode timing in VLPR, VLPW, and VLPS modes (full voltage range)**

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S11	I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)	250	—	ns
S12	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low (input)	45%	55%	MCLK period
S13	I2S_TX_FS/I2S_RX_FS input setup before I2S_TX_BCLK/I2S_RX_BCLK	30	—	ns
S14	I2S_TX_FS/I2S_RX_FS input hold after I2S_TX_BCLK/I2S_RX_BCLK	7.6	—	ns
S15	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output valid	—	67	ns
S16	I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output invalid	0	—	ns

Table continues on the next page...

**Table 50. TSI electrical specifications (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
I <sub>ELE</sub>	Electrode oscillator current source base current <ul style="list-style-type: none"> <li>• 2 μA setting (EXTCHRG = 0)</li> <li>• 32 μA setting (EXTCHRG = 15)</li> </ul>	— —	2 36	3 50	μA	2, 7
Pres5	Electrode capacitance measurement precision	—	8.3333	38400	fF/count	8
Pres20	Electrode capacitance measurement precision	—	8.3333	38400	fF/count	9
Pres100	Electrode capacitance measurement precision	—	8.3333	38400	fF/count	10
MaxSens	Maximum sensitivity	0.008	1.46	—	fF/count	11
Res	Resolution	—	—	16	bits	
T <sub>Con20</sub>	Response time @ 20 pF	8	15	25	μs	12
I <sub>TSI_RUN</sub>	Current added in run mode	—	55	—	μA	
I <sub>TSI_LP</sub>	Low power mode current adder	—	1.3	2.5	μA	13

1. The TSI module is functional with capacitance values outside this range. However, optimal performance is not guaranteed.
2. Fixed external capacitance of 20 pF.
3. REFCHRG = 2, EXTCHRG=0.
4. REFCHRG = 0, EXTCHRG = 10.
5. V<sub>DD</sub> = 3.0 V.
6. The programmable current source value is generated by multiplying the SCANC[REFCHRG] value and the base current.
7. The programmable current source value is generated by multiplying the SCANC[EXTCHRG] value and the base current.
8. Measured with a 5 pF electrode, reference oscillator frequency of 10 MHz, PS = 128, NSCN = 8; I<sub>ext</sub> = 16.
9. Measured with a 20 pF electrode, reference oscillator frequency of 10 MHz, PS = 128, NSCN = 2; I<sub>ext</sub> = 16.
10. Measured with a 20 pF electrode, reference oscillator frequency of 10 MHz, PS = 16, NSCN = 3; I<sub>ext</sub> = 16.
11. Sensitivity defines the minimum capacitance change when a single count from the TSI module changes. Sensitivity depends on the configuration used. The documented values are provided as examples calculated for a specific configuration of operating conditions using the following equation:  $(C_{ref} * I_{ext}) / (I_{ref} * PS * NSCN)$   
 The typical value is calculated with the following configuration:  
 I<sub>ext</sub> = 6 μA (EXTCHRG = 2), PS = 128, NSCN = 2, I<sub>ref</sub> = 16 μA (REFCHRG = 7), C<sub>ref</sub> = 1.0 pF  
 The minimum value is calculated with the following configuration:  
 I<sub>ext</sub> = 2 μA (EXTCHRG = 0), PS = 128, NSCN = 32, I<sub>ref</sub> = 32 μA (REFCHRG = 15), C<sub>ref</sub> = 0.5 pF  
 The highest possible sensitivity is the minimum value because it represents the smallest possible capacitance that can be measured by a single count.
12. Time to do one complete measurement of the electrode. Sensitivity resolution of 0.0133 pF, PS = 0, NSCN = 0, 1 electrode, EXTCHRG = 7.
13. REFCHRG=0, EXTCHRG=4, PS=7, NSCN=0F, LPSCNITV=F, LPO is selected (1 kHz), and fixed external capacitance of 20 pF. Data is captured with an average of 7 periods window.

## 6.9.2 LCD electrical characteristics

**Table 51. LCD electricals**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
f <sub>Frame</sub>	LCD frame frequency	28	30	58	Hz	
C <sub>LCD</sub>	LCD charge pump capacitance — nominal value	—	100	—	nF	1
C <sub>BYLCD</sub>	LCD bypass capacitance — nominal value	—	100	—	nF	1
C <sub>Glass</sub>	LCD glass capacitance	—	2000	8000	pF	2

Table continues on the next page...

## 8 Pinout

### 8.1 K51 Signal Multiplexing and Pin Assignments

The following table shows the signals available on each pin and the locations of these pins on the devices supported by this document. The Port Control Module is responsible for selecting which ALT functionality is available on each pin.

121 MAP BGA	100 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
E4	1	PTE0	ADC1_SE4a	ADC1_SE4a	PTE0	SPI1_PCS1	UART1_TX			I2C1_SDA	RTC_CLKOUT	
E3	2	PTE1/ LLWU_P0	ADC1_SE5a	ADC1_SE5a	PTE1/ LLWU_P0	SPI1_SOUT	UART1_RX			I2C1_SCL	SPI1_SIN	
E2	3	PTE2/ LLWU_P1	ADC1_SE6a	ADC1_SE6a	PTE2/ LLWU_P1	SPI1_SCK	UART1_CTS_ b					
F4	4	PTE3	ADC1_SE7a	ADC1_SE7a	PTE3	SPI1_SIN	UART1_RTS_ b				SPI1_SOUT	
E7	—	VDD	VDD	VDD								
F7	—	VSS	VSS	VSS								
H7	5	PTE4/ LLWU_P2	DISABLED		PTE4/ LLWU_P2	SPI1_PCS0	UART3_TX					
G4	6	PTE5	DISABLED		PTE5	SPI1_PCS2	UART3_RX					
E6	7	VDD	VDD	VDD								
G7	8	VSS	VSS	VSS								
L6	—	VSS	VSS	VSS								
F1	9	USB0_DP	USB0_DP	USB0_DP								
F2	10	USB0_DM	USB0_DM	USB0_DM								
G1	11	VOUT33	VOUT33	VOUT33								
G2	12	VREGIN	VREGIN	VREGIN								
H1	13	ADC0_DP1/ OP0_DP0	ADC0_DP1/ OP0_DP0	ADC0_DP1/ OP0_DP0								
H2	14	ADC0_DM1/ OP0_DM0	ADC0_DM1/ OP0_DM0	ADC0_DM1/ OP0_DM0								
J1	15	ADC1_DP1/ OP1_DP0/ OP1_DM1	ADC1_DP1/ OP1_DP0/ OP1_DM1	ADC1_DP1/ OP1_DP0/ OP1_DM1								
J2	16	ADC1_DM1/ OP1_DM0	ADC1_DM1/ OP1_DM0	ADC1_DM1/ OP1_DM0								
K1	17	PGA0_DP/ ADC0_DPO/ ADC1_DP3	PGA0_DP/ ADC0_DPO/ ADC1_DP3	PGA0_DP/ ADC0_DPO/ ADC1_DP3								
K2	18	PGA0_DM/ ADC0_DM0/ ADC1_DM3	PGA0_DM/ ADC0_DM0/ ADC1_DM3	PGA0_DM/ ADC0_DM0/ ADC1_DM3								

121 MAP BGA	100 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
B5	—	NC	NC	NC								
B1	—	NC	NC	NC								
C2	—	NC	NC	NC								
C1	—	NC	NC	NC								
D2	—	NC	NC	NC								
D1	—	NC	NC	NC								
E1	—	NC	NC	NC								

## 8.2 K51 Pinouts

The below figure shows the pinout diagram for the devices supported by this document. Many signals may be multiplexed onto a single pin. To determine what signals can be used on which pin, see the previous section.

	1	2	3	4	5	6	7	8	9	10	11	
A	PTD7	PTD5	PTD4/ LLWU_P14	PTC19	PTC14	PTC13	PTC8	PTC4/ LLWU_P8	VLL1	VLL2	VLL3	A
B	NC	PTD6/ LLWU_P15	PTD3	PTC18	NC	PTC12	PTC7	PTC3/ LLWU_P7	PTC0	PTB16	VCAP2	B
C	NC	NC	PTD2/ LLWU_P13	PTC17	PTC11/ LLWU_P11	PTC10	PTC6/ LLWU_P10	PTC2	PTB19	PTB11	VCAP1	C
D	NC	NC	PTD1	PTD0/ LLWU_P12	PTC16	PTC9	PTC5/ LLWU_P9	PTC1/ LLWU_P6	PTB18	PTB10	PTB8	D
E	NC	PTE2/ LLWU_P1	PTE1/ LLWU_P0	PTE0	VDD	VDD	VDD	PTB23	PTB17	PTB9	PTB7	E
F	USB0_DP	USB0_DM	NC	PTE3	VDDA	VSSA	VSS	PTB22	PTB21	PTB20	NC	F
G	VOUT33	VREGIN	VSS	PTE5	VREFH	VREFL	VSS	PTB3	PTB2	PTB1	PTB0/ LLWU_P5	G
H	ADC0_DP1/ OP0_DP0	ADC0_DM1/ OP0_DM0	ADC0_SE16/ OP0_OUT1/ ADC0_SE21/ OP0_DP1/ OP1_DP1	TRIO_DM	NC	CMP2_IN5/ ADC1_SE22	PTE4/ LLWU_P2	PTA1	PTA3	NC	NC	H
J	ADC1_DP1/ OP1_DP0/ OP1_DM1	ADC1_DM1/ OP1_DM0	ADC1_SE16/ OP1_OUT1/ CMP2_IN2/ ADC0_SE22/ OP0_DP2/ OP1_DP2	TRIO_DP	NC	PTA0	PTA2	PTA4/ LLWU_P3	NC	NC	RESET_b	J
K	PGA0_DP/ ADC0_DP0/ ADC1_DP3	PGA0_DM/ ADC0_DM0/ ADC1_DM3	TRIO_OUT/ OP1_DM2	CMP0_IN4/ ADC1_SE23/ OP0_DP5/ OP1_DP5	DAC0_OUT/ CMP1_IN3/ ADC0_SE23/ OP0_DP4/ OP1_DP4	VBAT	NC	PTA12	PTA14	VSS	PTA19	K
L	PGA1_DP/ ADC1_DP0/ ADC0_DP3	PGA1_DM/ ADC1_DM0/ ADC0_DM3	VREF_OUT/ CMP1_IN5/ CMP0_IN5/ ADC1_SE18	XTAL32	EXTAL32	VSS	RTC WAKEUP_B	PTA13/ LLWU_P4	PTA15	VDD	PTA18	L
	1	2	3	4	5	6	7	8	9	10	11	

Figure 28. K51 121 MAPBGA Pinout Diagram

## 9 Revision History

The following table provides a revision history for this document.

**Table 52. Revision History**

Rev. No.	Date	Substantial Changes
1	3/2012	Initial public release

Table continues on the next page...